

# T2SLS Digital Focal Plane Arrays for Earth Remote Sensing Instruments

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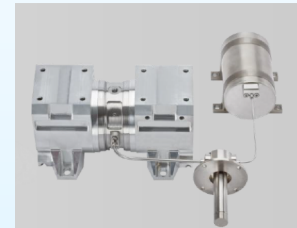
# Outline

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- High Operating Temperature Barrier Infrared Detectors (HOT-BIRDS) technology
  - Decrease detector dark current (i.e., reduce noise -> increase SNR)
- Resonator Pixel (RP) light coupling technology
  - Increase detector quantum efficiency (i.e., increase SNR)
- 3D-Digital read out integrated circuits (DROICs) technology
  - Increases the ROIC well depth (i.e., reduce noise -> increase SNR)

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- 3D-Digital read out integrated circuits (DROICs) technology
  - Increases the ROIC well depth (i.e., reduce noise -> increase SNR)
- Digital RP-BIRD focal plane arrays
  - Increases SNR or increases operating temperature for same SNR
  - Reduce the Size, Weight, and Power (SWaP) factor of the Integrated Detector Dewar Cooler Assembly (IDDCa) -> Enables SmallSat applications
  - Digital RP-BIRD MWIR at 200K & LWIR at 100K for broadband imaging
  - SF-400: 2W, 100W, 3.8Kg whereas SF-070: 800mW, 40W, 0.85Kg



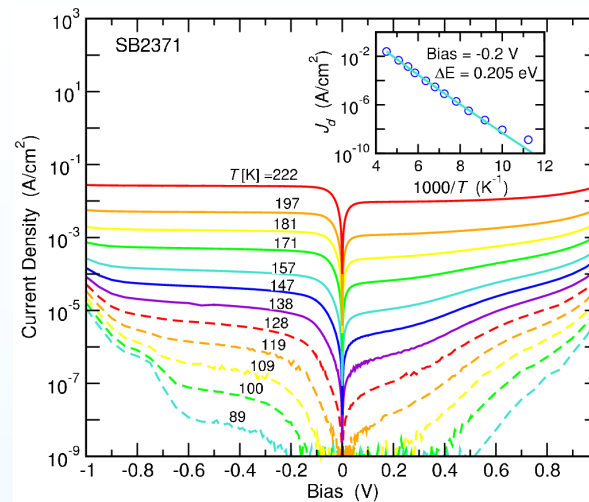
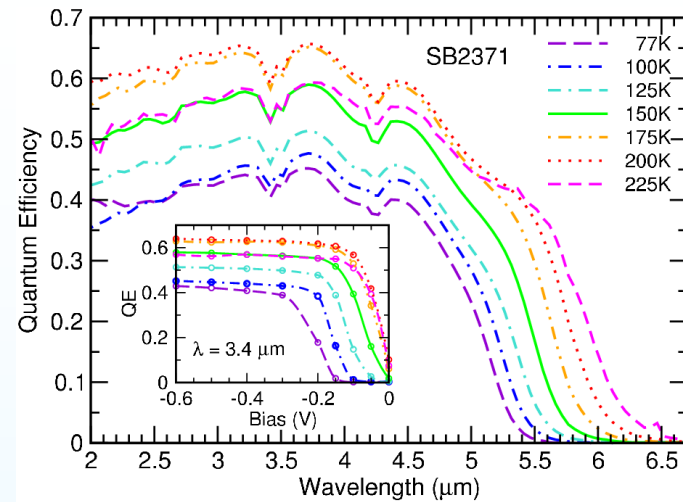
SF-400



SF-070

# Barrier Infrared Detector Technology

# MWIR InAs/InAsSb T2SLS High Operating Temperature Barrier IR Detector (HOT-BIRD)

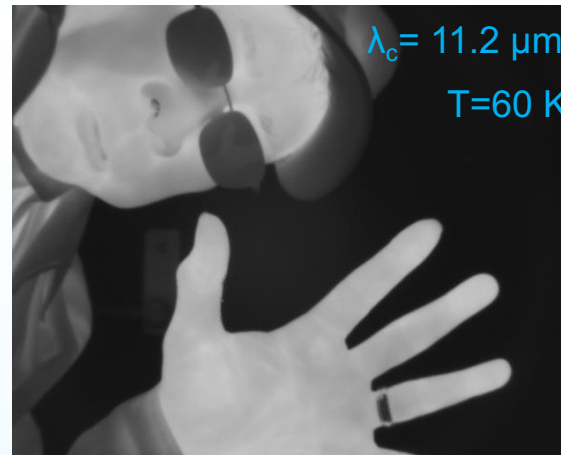
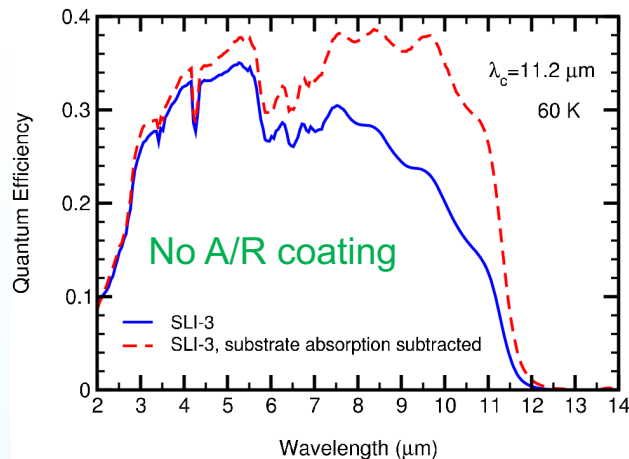


- $\text{QE}(4.3 \mu\text{m}, 150\text{K}) = 52\%$  – No A/R coating
- $J_{\text{dark}}(-0.2\text{V}, 157\text{K}) = 9.6 \times 10^{-5} \text{ A/cm}^2$  ( $\sim 4.5\text{X}$  Rule'07)
- 160K: NEDT 18.7 mK, Operability 99.7%
- 170K: NEDT 26.6 mK, Operability 99.6%
- FPA shows **significantly higher operating temperature than InSb**

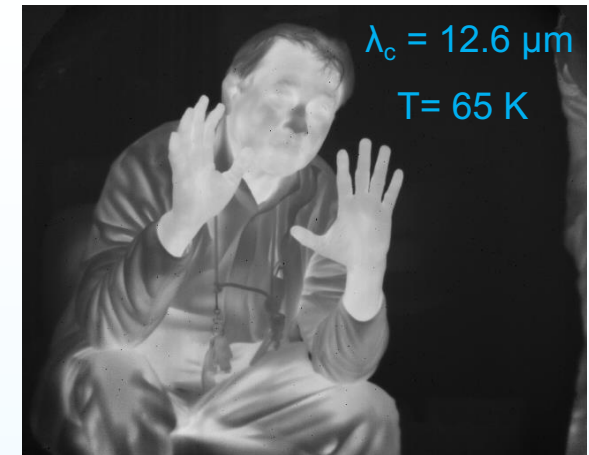
“**Barrier InfraRed Detectors**”, D. Z. Ting, A. Khoshakhlagh, A. Soibel, Cory J. Hill, and S. D. Gunapala, U. S. Patent No. 8,217,480 (2012)

**HOT-BIRD**: “Mid-wavelength **high operating temperature barrier infrared detector and focal plane array**”, D. Z. Ting, A. Soibel, A. Khoshakhlagh, S. B. Rafol, S. A. Keo, L. Höglund, A. M. Fisher, E. M. Luong, and S. D. Gunapala, *Appl. Phys. Lett.* **113**, 021101 (2018). doi: 10.1063/1.5033338

# LWIR T2SL Detectors & FPAs



99.7% operability (17SLL03)



99.98% operability (18SLL03)

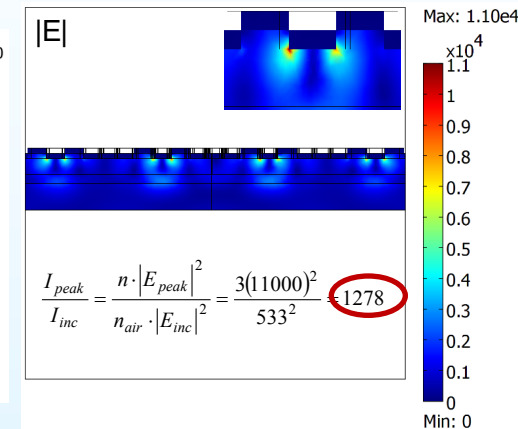
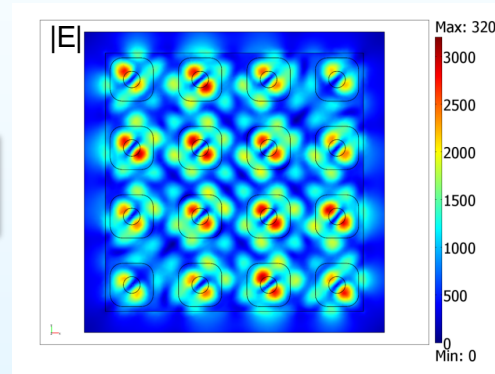
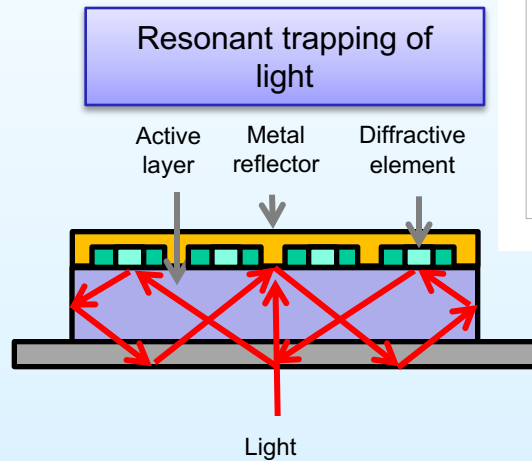
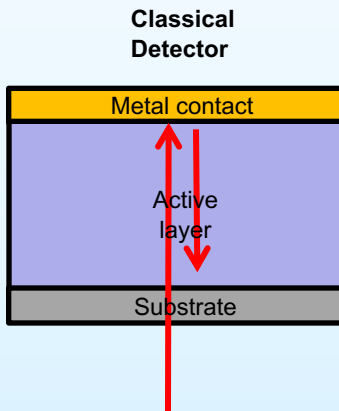
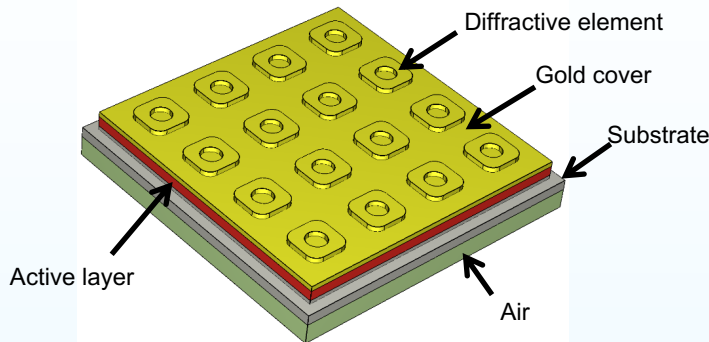
- Developing T2SL-based LWIR detectors for NASA Sustainable Land Imaging Technology (SLI-T) Program
- Unipolar barrier infrared detector architecture, T2SL absorber
  - High quality  $\lambda_{\text{cutoff}} \sim 11.2 \mu\text{m}$  T2SL absorber material
  - 240 ns minority carrier lifetime
  - $J_{\text{dark}}(60\text{K}) \sim 10^{-5} \text{ A/cm}^2$  ; QE  $\sim 37\%$  without A/R coating.
  - Very good FPA operabilities
- Also demonstrated  $\lambda_{\text{cutoff}} \sim 12.6 \mu\text{m}$  detectors/FPAs

# Resonator Pixel Technology

# Resonator-Pixel Technology

## Concept:

- Diffract incident light at an angle larger than the **critical angle** of total internal reflection to achieve three-dimensional optical confinement.
- Use pixel active volume as a resonator to achieve coherent accumulation of light.

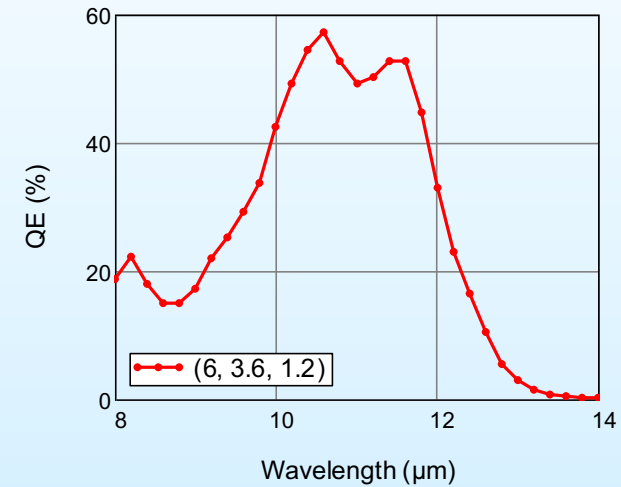
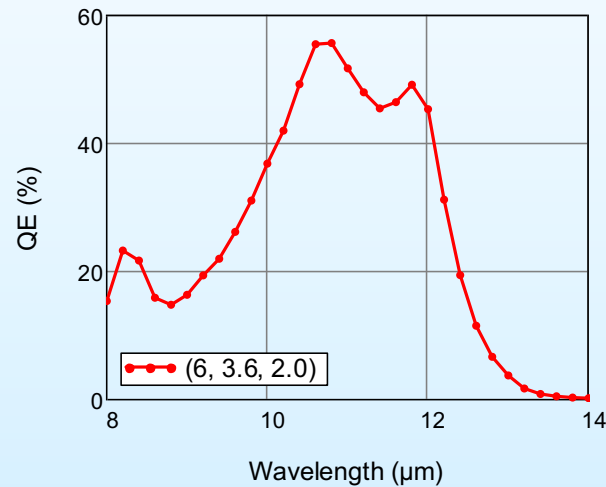
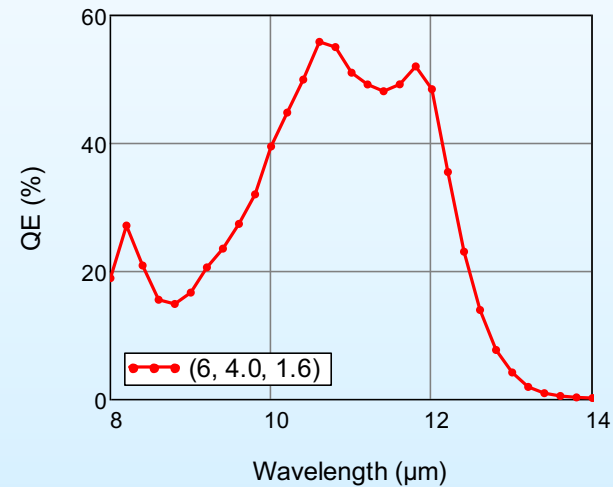
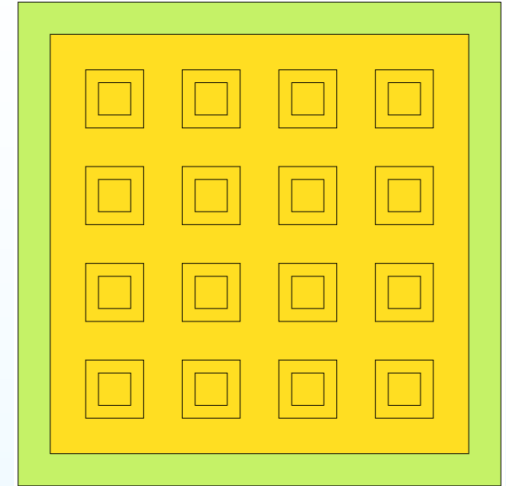
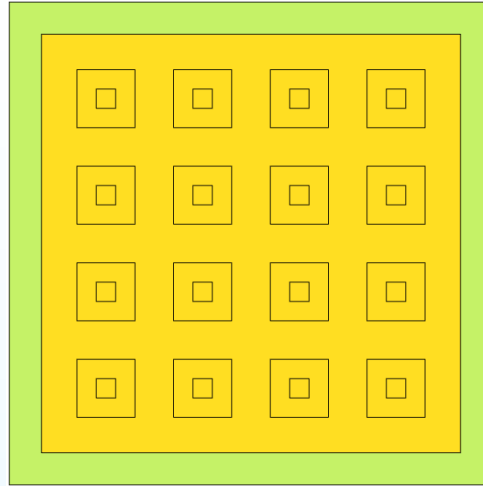
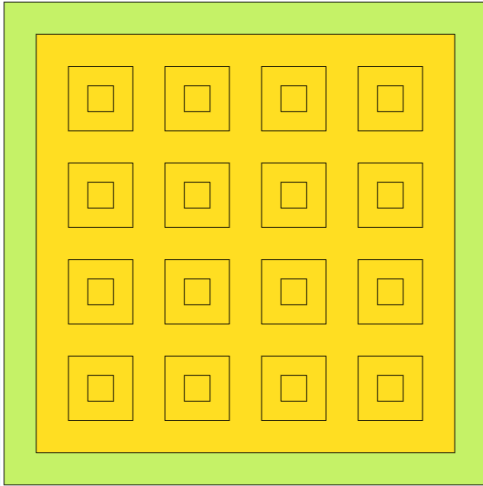


## Advantages:

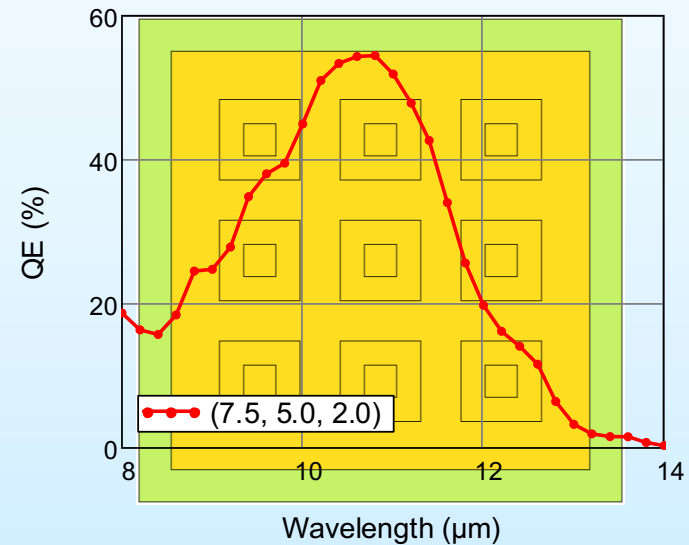
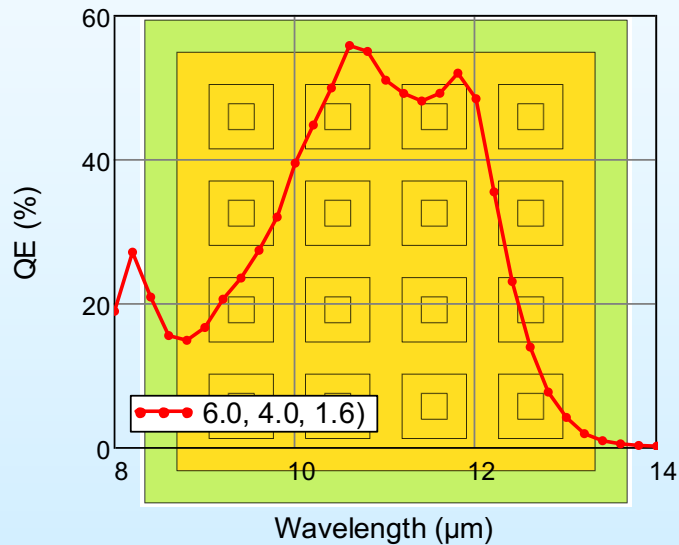
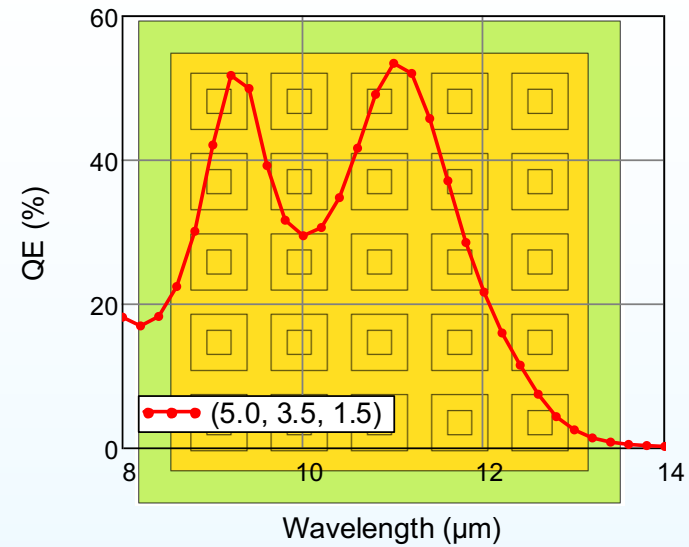
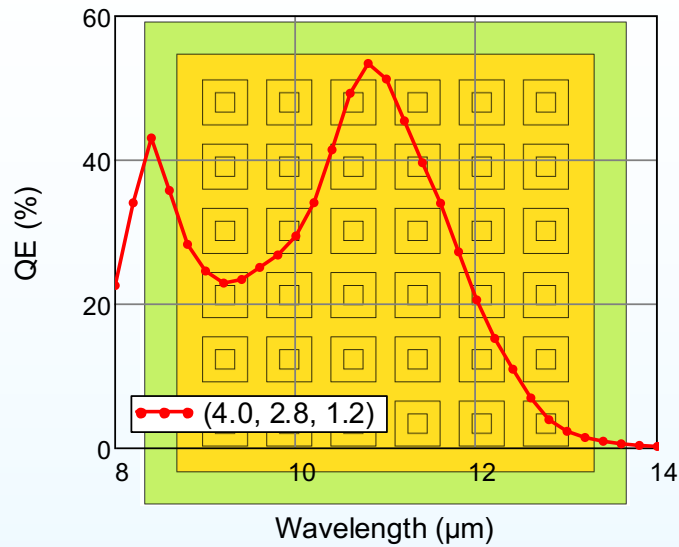
- Increases quantum efficiency
- Thin active layers (good for low carrier mobility)
- Low dark current (due to thin pixel)
- Free of anti-reflection coating



# RP-BIRD, 6 $\mu\text{m}$ Period

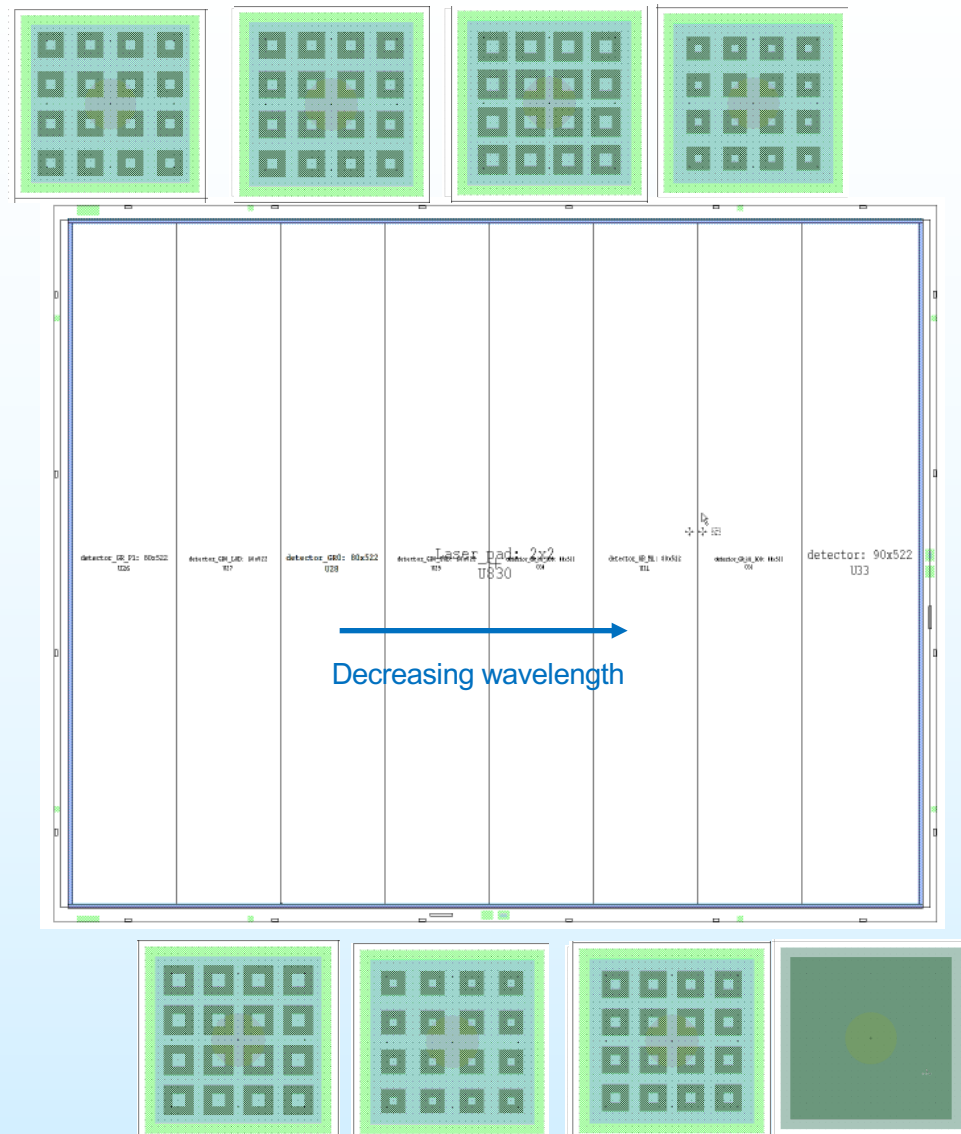


# QE Spectrum with $n \times n$ Rings



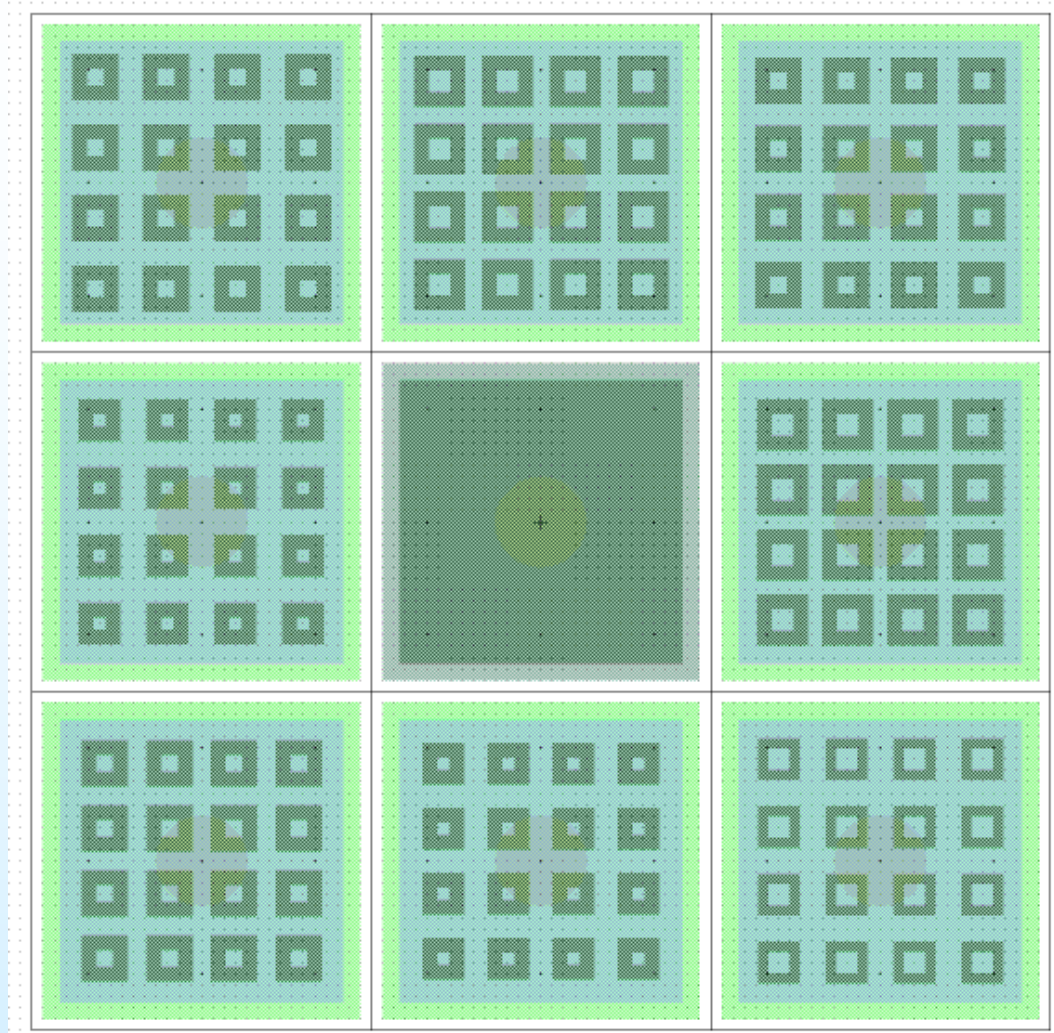
# ISC 0903 DA Layout #3 - Stripes

- Vertical arrangement
- 8 different designs for 40x256 stripes on the array
- Longest wavelength on the left



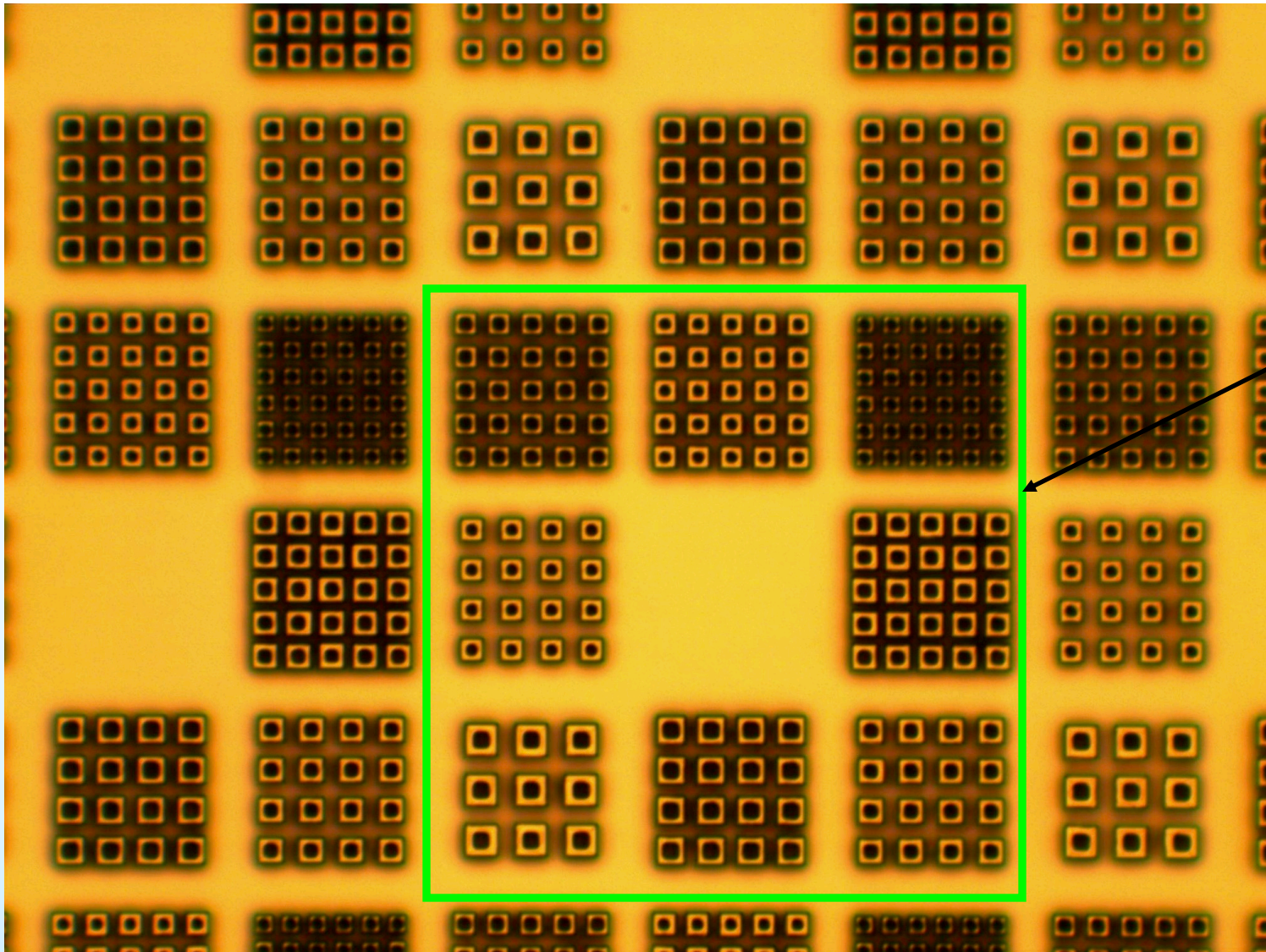
# ISC 0903 FPA Layout #4 - Superpixel

- 3x3 superpixel, pick out sub-frames with matlab
- Not as visceral as the stripes, but it's a good option to see all pixels uniformly distributed
- Could mix a few of these in with the striped ones
- Would have entire images to compare instead of stripes





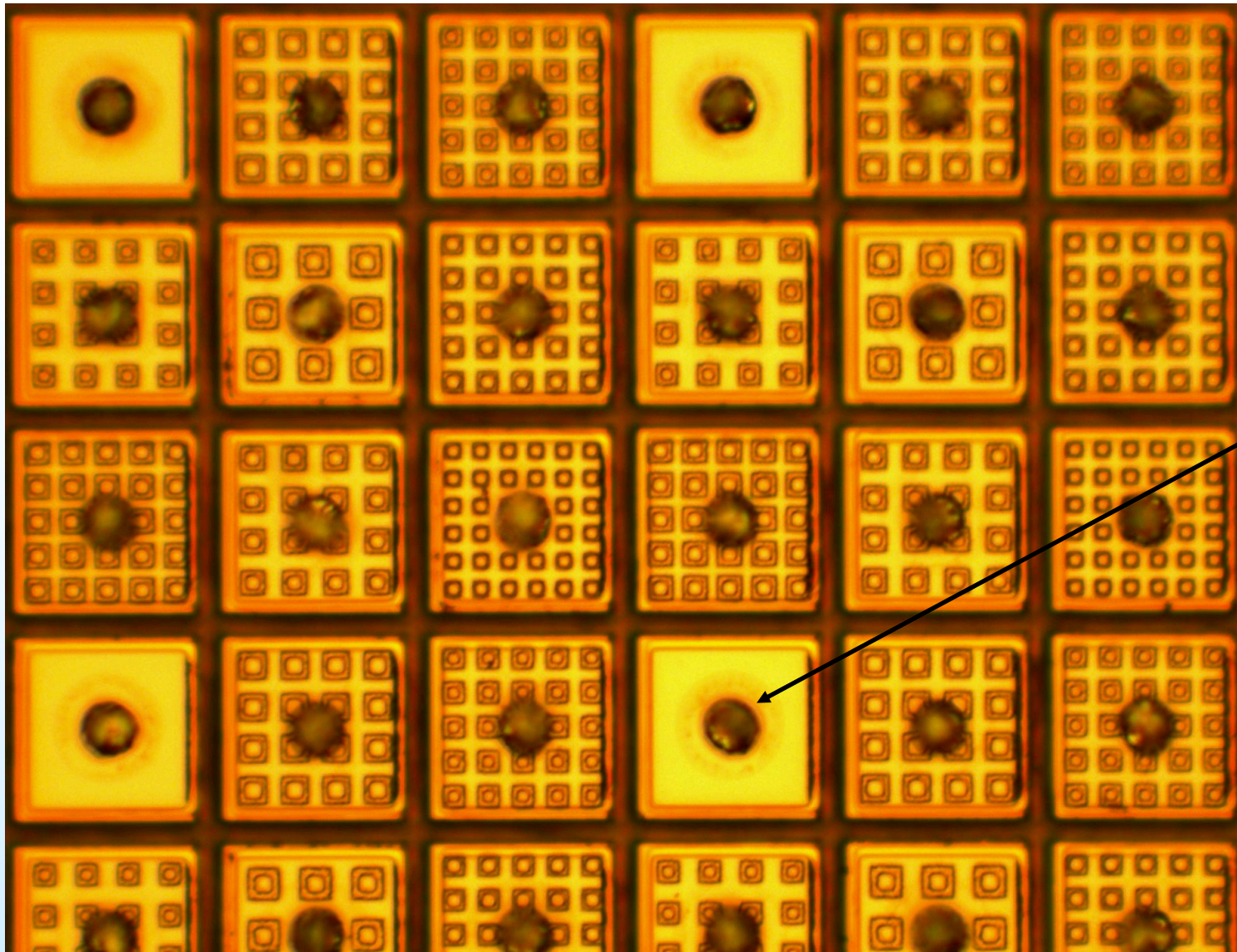
# Micrograph of Detector Array



Superpixel



# Micrograph of Detector Array with In Bumps



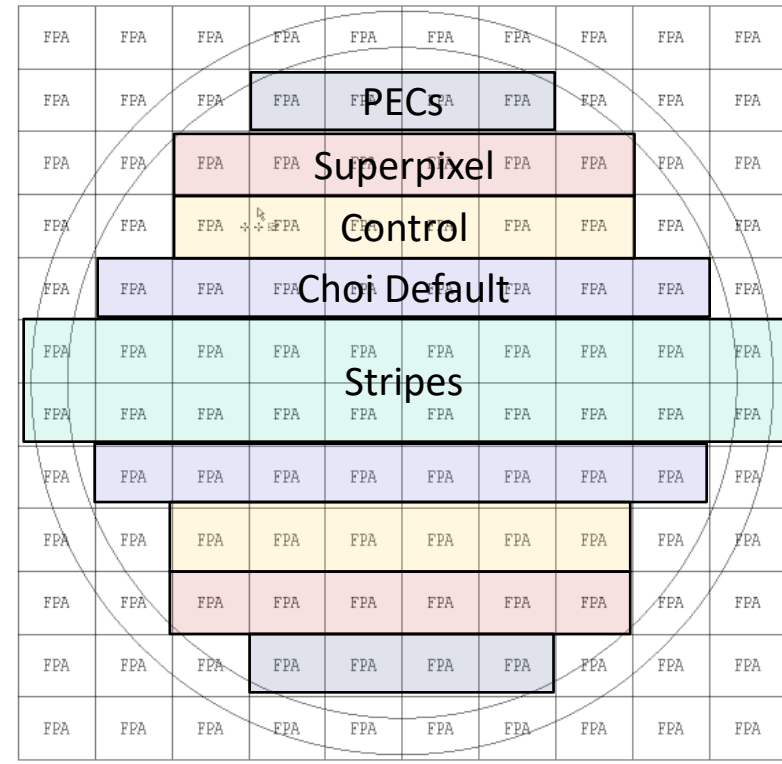
Indium Bumps

# ISC 0903 based Detector Array Reticle Layout

Wafer layout – can mix and match FPA designs and process evaluation chips (PECs)

Four permutations on the grating layer

- Normal (no grating)
- Choi's default
- 1x8 stripe (normal+7)
- 3x3 superpixel

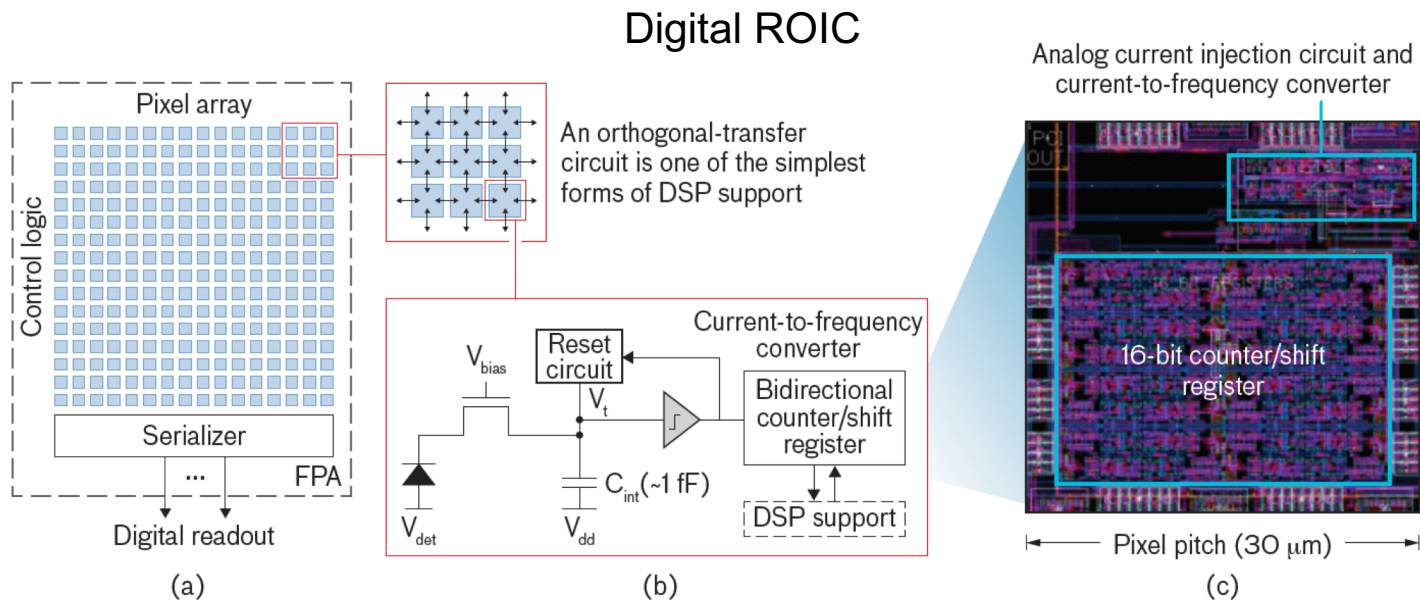
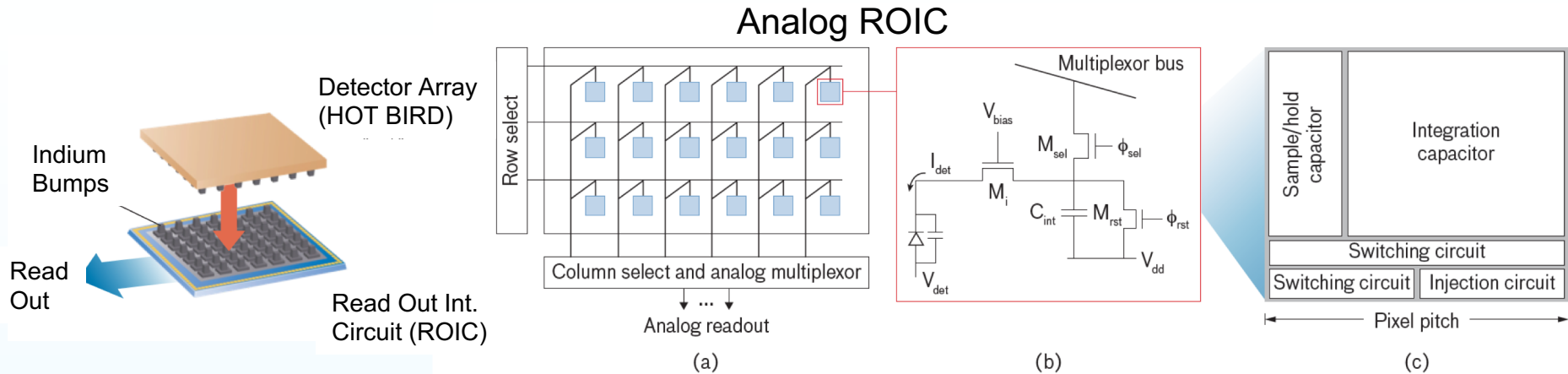


Number of ISC 0903 detector arrays (DAs) on a 4" wafer

# Digital Pixel Read Out Electronic Circuit (DROIC) Technology

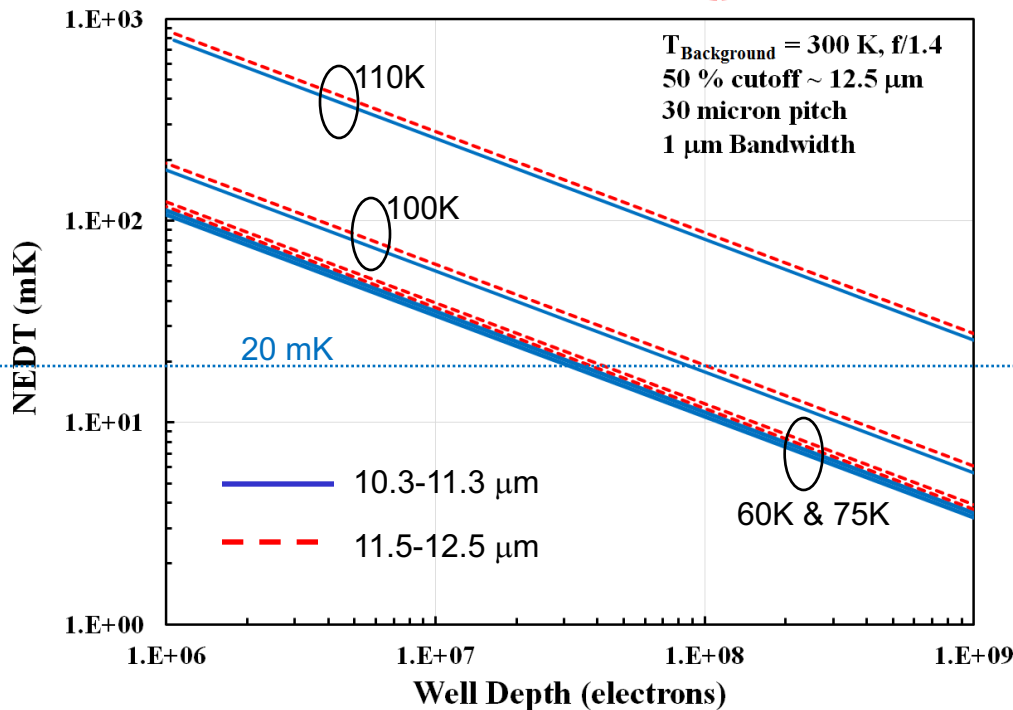


# Digital Read Out Integrated Circuits (DROICs)



# Case Study: Digital BIRD FPA for Land Imaging to Meet New Challenges (Imager)

ROIC	ISC-9803 AROIC	ISC-0905 AROIC	DRS 3D-DROIC	DRS 3D-DROIC	DRS 3D-DROIC
Binning	1×1	1×1	1×1	3×3	4×4
ROIC Format	640×512	640×512	2004×2008	668×668 (eff.)	501×502 (eff.)
Pixel Pitch	25 μm	30 μm	8 μm	24 μm (eff.)	32 μm (eff.)
Well Depth	11 Me <sup>-</sup>	18 Me <sup>-</sup>	173 Me <sup>-</sup>	1,560 Me <sup>-</sup> (eff.)	2,780 Me <sup>-</sup> (eff.)

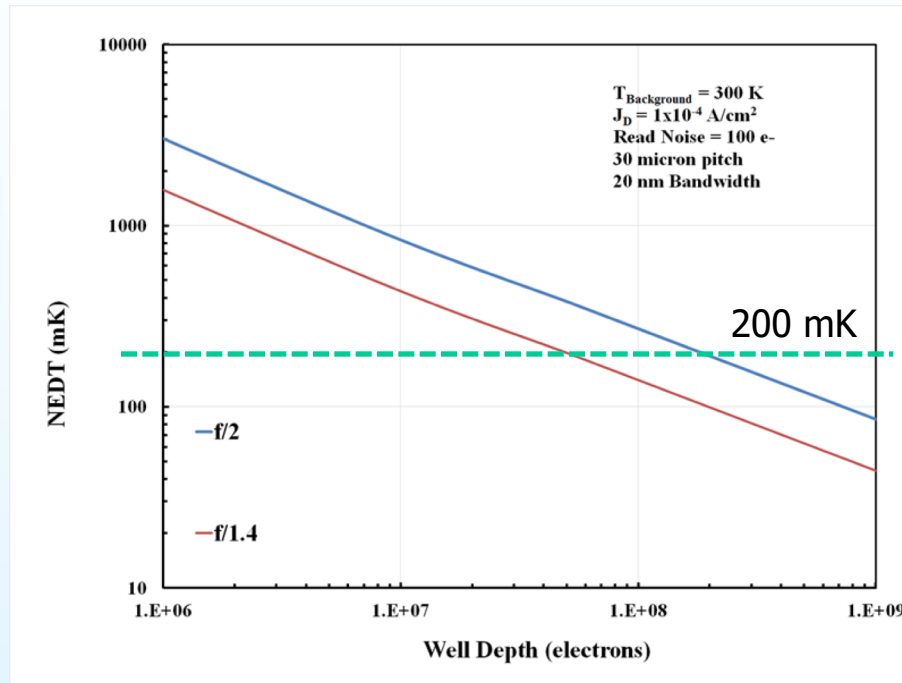


$$SNR_{Max} = \frac{Signal_{Max}}{Noise} = \sqrt{Well Depth_{Max}}$$

- BIRD for improved detector dark current and QE performance over QWIP (i.e., 43K)
- Digital-pixel ROIC with large well depth enables much longer integration time to improve signal to noise ratio
  - Conventional ROIC well depth ~ few million e<sup>-</sup>s
  - D-ROIC well depth can exceed 1 billion e<sup>-</sup>s
- Can achieve 20 mK NEDT for 500 nm wide spectral band centered at 10 – 12.5 μm only with D-ROIC large well depth

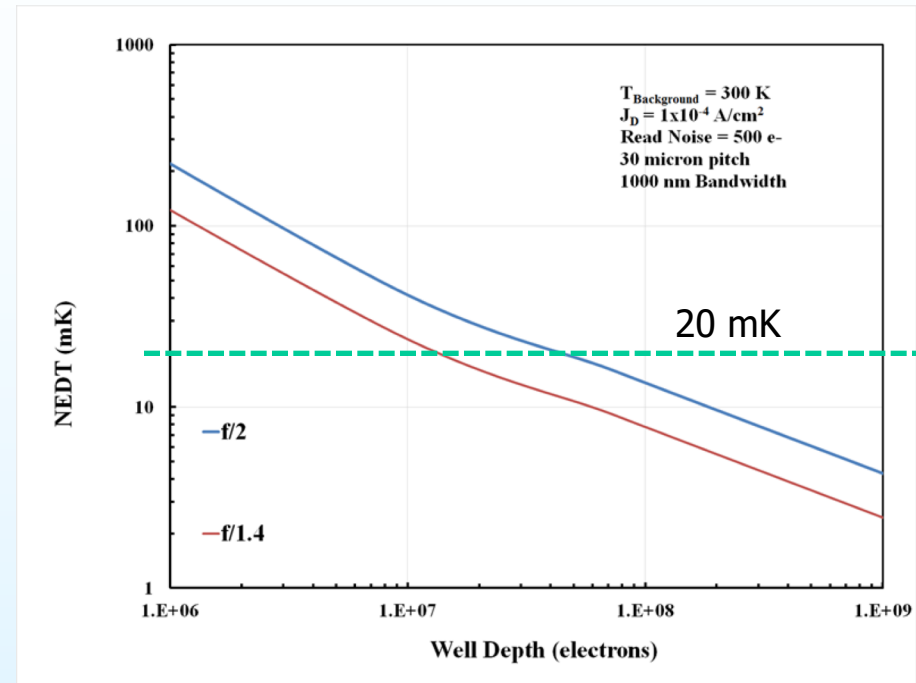
# Estimated MWIR Performance with DROICs

For Spectrometers



Center Wavelength  $4.5 \pm 0.01 \mu\text{m}$   
 Operating Temperature 200 K

For Thermal Imagers



Wavelength Bandwidth  $3.5\text{-}4.5 \mu\text{m}$   
 Operating Temperature 200 K

# Summary

- Recent advances in HOT Barrier IR Detector (BIRD) technology is a breakthrough
  - Elevated the FPA operating temperature, good uniformity & operability, and good manufacturability
- Resonator Pixel technology
  - Will increase quantum efficiency
- Digital ROIC is a breakthrough technology
  - Elevates operating temperature
- RP-BIRD DFPA elevates the operating temperature of FPAs
  - Lowers the SWaP factor
  - Enables the low cost Cubesats & Smallsats (for IR land imaging, Spectrometers, and sounders)
  - 200K for MWIR and 100K for LWIR for broadband land imaging
- This work is sponsored by NASA ESTO under ACT program

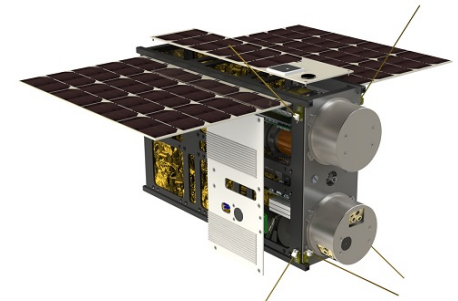
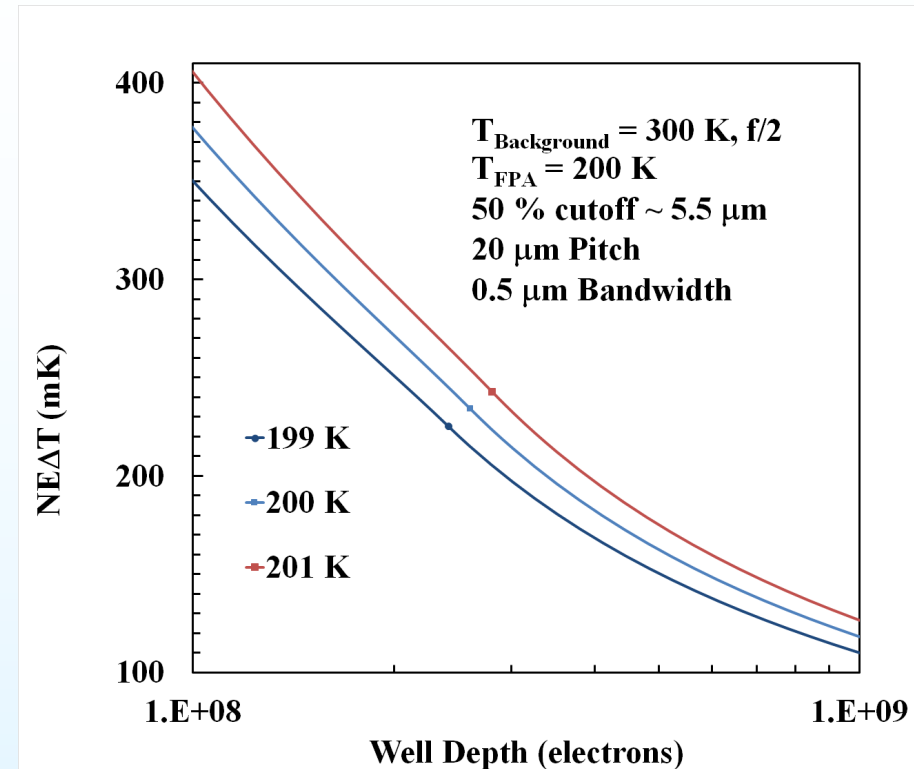
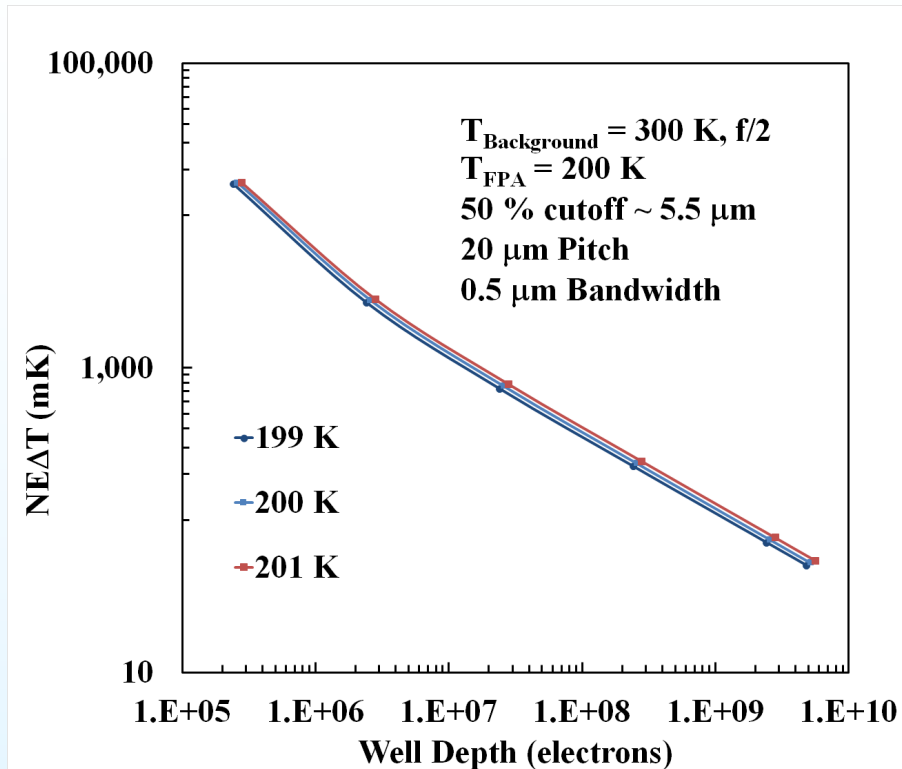


Image Credit: <https://n-avionics.com/>

# Backup Slides

# Spectral Bandwidth $0.5 \mu\text{m}$ about $5 \mu\text{m}$ center

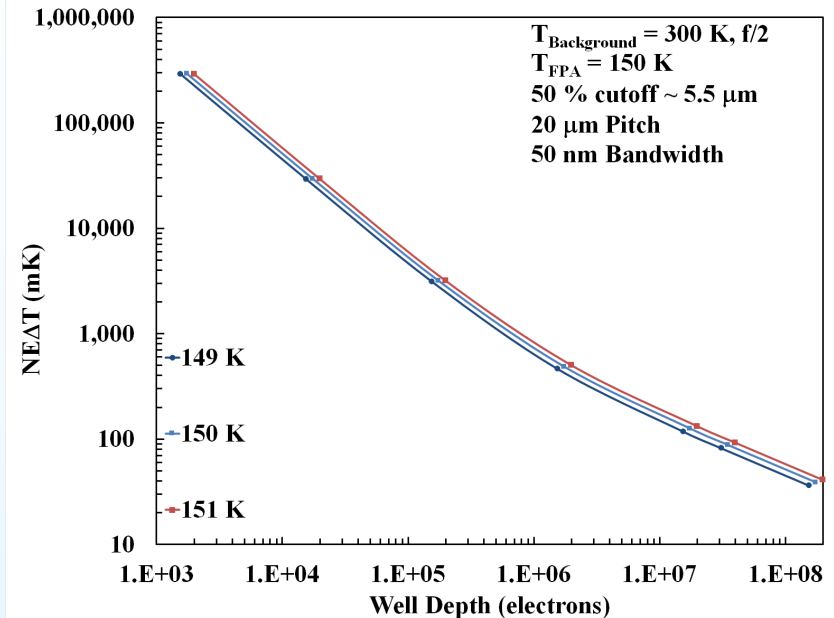
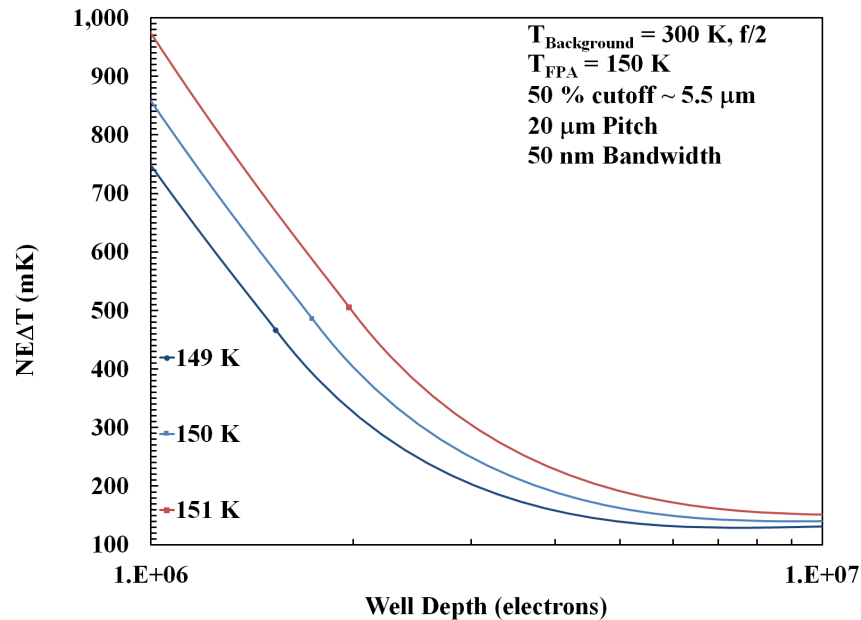


Smaller Fluctuation in NE $\Delta$ T at longer integration time or deeper well than in shorter integration time or shallower well. For example, at  $10^9$  electrons well depth, NE $\Delta$ T fluctuation  $\sim 17 \text{ mK}$  peak-to-peak and at  $2 \times 10^8$  electrons well depth, NE $\Delta$ T fluctuation  $\sim 55 \text{ mK}$  peak-to-peak for  $\pm 1 \text{ K}$  variation about the operating temperature of 200 K.



# Spectral Bandwidth 50 nm about 5 $\mu\text{m}$ center

Jet Propulsion Laboratory  
California Institute of Technology



Smaller Fluctuation in  $\text{NE}\Delta T$  at longer integration time or deeper well than in shorter integration time or shallower well. For example, at  $10^7$  electrons well depth,  $\text{NE}\Delta T$  fluctuation  $< 30 \text{ mK}$  peak-to-peak and at  $1 \times 10^6$  electrons well depth,  $\text{NE}\Delta T$  fluctuation  $< 230 \text{ mK}$  peak-to-peak for  $\pm 1 \text{ K}$  variation about the operating temperature of 150 K.